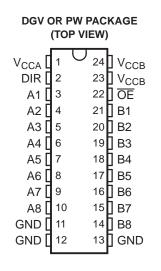


FEATURES

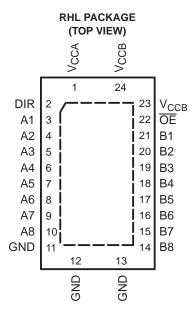
- Control Inputs V_{IH}/V_{IL} Levels Are Referenced to V_{CCA} Voltage
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, All I/O Ports Are in the High-Impedance State
- I_{off} Supports Partial-Power-Down Mode Operation
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.2-V to 3.6-V Power-Supply Range
- I/Os Are 4.6-V Tolerant



• Max Data Rates:

- 320 Mbps (V_{CCA} \geq 1.8 V and V_{CCB} \geq 1.8 V)

- 170 Mbps ($V_{CCA} \le 1.8$ V or $V_{CCB} \le 1.8$ V)
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 8000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



DESCRIPTION/ORDERING INFORMATION

This 8-bit noninverting bus transceiver uses two separate configurable power-supply rails. The SN74AVCH8T245 is optimized to operate with V_{CCA}/V_{CCB} set at 1.4 V to 3.6 V. It is operational with V_{CCA}/V_{CCB} as low as 1.2 V. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB} . Accepts any supply voltage from 1.2 V to 3.6 V. This allows for universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

ORDERING INFORMATION

T _A	PAC	CKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RHL	Reel of 1000	SN74AVCH8T245RHLR	WP245
-40°C to 85°C	TSSOP – PW	Tube of 60	SN74AVCH8T245PW	- WP245
-40 C 10 85 C	1330F - FW	Reel of 2000	SN74AVCH8T245PWR	VVF243
	TVSOP – DGV	Reel of 2000	SN74AVCH8T245DGVR	WP245

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SCES565G-APRIL 2004-REVISED MARCH 2007

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The SN74AVCH8T245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the outputs so the buses are effectively isolated.

The SN74AVCH8T245 is designed so the control pins (DIR and \overline{OE}) are supplied by V_{CCA}.

The SN74AVCH8T245 solution is compatible with a single-supply system and can be replaced later with a '245 function, with minimal printed circuit board redesign.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, both outputs are in the high-impedance state. The bus-hold circuitry on the powered-up side always stays active.

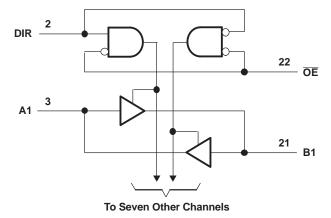
Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

To ensure the high-impedance state during power up or power down, OE shall be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE (each 8-bit section)

INP	UTS	OPERATION
ŌĒ	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
н	Х	All output Hi-Z

LOGIC DIAGRAM (POSITIVE LOGIC)



SCES565G-APRIL 2004-REVISED MARCH 2007

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage range		-0.5	4.6	V
		I/O ports (A port)	-0.5	4.6	
VI	Input voltage range ⁽²⁾	I/O ports (B port)	-0.5	4.6	V
		Control inputs	-0.5	4.6	
V	Voltage range applied to any output	A port	-0.5	4.6	V
Vo	in the high-impedance or power-off state ⁽²⁾	B port	-0.5	4.6	V
	V(a) to be a set of the set of the birth of the birth of the set of (2)	A port	-0.5 V	_{CCA} + 0.5	V
Vo	Voltage range applied to any output in the high or low state $^{(2)(3)}$	B port	-0.5 V	ссв + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CCA} , V _{CCB} , or GND			±100	mA
		DGV package		86	
θ_{JA}	Package thermal impedance ⁽⁴⁾	PW package		88	°C/W
		RHL package	43		
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating" conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
 (3) The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

SCES565G-APRIL 2004-REVISED MARCH 2007

Recommended Operating Conditions⁽¹⁾⁽²⁾⁽³⁾

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V _{CCA}	Supply voltage				1.2	3.6	V
V _{CCB}	Supply voltage				1.2	3.6	V
			1.2 V to 1.95 V		$V_{CCI} imes 0.65$		
VIH	High-level input voltage	Data inputs	1.95 V to 2.7 V		1.6		V
	input voltage		2.7 V to 3.6 V		2		
			1.2 V to 1.95 V			$V_{CCI}\ \times 0.35$	
VIL	Low-level input voltage	Data inputs	1.95 V to 2.7 V			0.7	V
	input voltage		2.7 V to 3.6 V			0.8	
			1.2 V to 1.95 V		$V_{CCA} imes 0.65$		
VIH	High-level input voltage	DIR (referenced to V _{CCA})	1.95 V to 2.7 V		1.6		V
	input voltago		2.7 V to 3.6 V		2		
			1.2 V to 1.95 V			$V_{\text{CCA}} \times 0.35$	
VIL	Low-level input voltage	DIR (referenced to V _{CCA})	1.95 V to 2.7 V			0.7	V
	input voltage	(Telefeneed to VCCA)	2.7 V to 3.6 V			0.8	
VI	Input voltage				0	3.6	V
\ <i>\</i>	Output voltogo	Active state			0	V _{CCO}	V
Vo	Output voltage	3-state			0	3.6	V
				1.2 V		-3	
				1.4 V to 1.6 V		-6	
I _{OH}	High-level output cu	irrent		1.65 V to 1.95 V		-8	mA
				2.3 V to 2.7 V		-9	
				3 V to 3.6 V		-12	
				1.2 V		3	
				1.4 V to 1.6 V		6	
I _{OL}	Low-level output curre	rrent		1.65 V to 1.95 V		8	mA
<i></i>				2.3 V to 2.7 V		9	
				3 V to 3.6 V		12	
Δt/Δv	Input transition rise	or fall rate				5	ns/V
T _A	Operating free-air te	emperature			-40	85	°C

V_{CCI} is the V_{CC} associated with the input port.
 V_{CCO} is the V_{CC} associated with the output port.
 All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

SCES565G-APRIL 2004-REVISED MARCH 2007

Electrical Characteristics⁽¹⁾⁽²⁾

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		v	v	٦	Γ _A = 25°C		–40°C to 8	5°C	UNIT	
PARAMETER	TEST COND	TIONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNI	
	I _{OH} = -100 μA		1.2 V to 3.6 V	1.2 V to 3.6 V				V _{CCO} - 0.2			
	I _{OH} = -3 mA		1.2 V	1.2 V		0.95					
N/	I _{OH} = -6 mA	$V_{I} = V_{IH}$	1.4 V	1.4 V				1.05		V	
V _{OH}	I _{OH} = -8 mA	$v_{I} = v_{IH}$	1.65 V	1.65 V				1.2		v	
	I _{OH} = -9 mA		2.3 V	2.3 V				1.75			
	I _{OH} = -12 mA		3 V	3 V				2.3			
	I _{OL} = 100 μA		1.2 V to 3.6 V	1.2 V to 3.6 V					0.2		
	$I_{OL} = 3 \text{ mA}$		1.2 V	1.2 V		0.15					
M	$I_{OL} = 6 \text{ mA}$	$V_{I} = V_{IL}$	1.4 V	1.4 V					0.35	V	
V _{OL}	I _{OL} = 8 mA	$v_{I} = v_{IL}$	1.65 V	1.65 V					0.45	v	
	I _{OL} = 9 mA		2.3 V	2.3 V					0.55		
	I _{OL} = 12 mA		3 V	3 V					0.7		
I _I Control inputs	$V_{I} = V_{CCA} \text{ or } GN$	ND	1.2 V to 3.6 V	1.2 V to 3.6 V		±0.025	±0.25		±1	μA	
BHL ⁽³⁾	V _I = 0.42 V		1.2 V	1.2 V		25					
	V _I = 0.49 V		1.4 V	1.4 V				15			
	V _I = 0.58 V		1.65 V	1.65 V				25		μA	
	V _I = 0.7 V		2.3 V	2.3 V				45			
	V _I = 0.8 V		3.3 V	3.3 V				100	15 25 15 00		
	V _I = 0.78 V		1.2 V	1.2 V		-25					
	V _I = 0.91 V		1.4 V	1.4 V				–15			
I _{BHH} ⁽⁴⁾	V _I = 1.07 V		1.65 V	1.65 V				-25		μA	
	V _I = 1.6 V		2.3 V	2.3 V				-45			
	V _I = 2 V		3.3 V	3.3 V				-100			
			1.2 V	1.2 V		50					
			1.6 V	1.6 V				125			
I _{BHLO} ⁽⁵⁾	$V_I = 0$ to V_{CC}		1.95 V	1.95 V				200		μA	
			2.7 V	2.7 V				300			
			3.6 V	3.6 V				500			
			1.2 V	1.2 V		-50					
			1.6 V	1.6 V				-125			
I _{BHHO} ⁽⁶⁾	$V_I = 0$ to V_{CC}		1.95 V	1.95 V				-200		μA	
			2.7 V	2.7 V	$\pm 0.025 \pm 0.25$						
		3.6 V	3.6 V				-500				

V_{CCI} is the V_{CC} associated with the input port.
 V_{CCO} is the V_{CC} associated with the output port.
 The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to (4) V_{CC} and then lowering it to V_{IH} min.

(5) An external driver must source at least I_{BHLO} to switch this node from low to high. (6) An external driver must sink at least I_{BHHO} to switch this node from high to low.

Electrical Characteristics (continued)⁽¹⁾⁽²⁾

over recommended operating free-air temperature range (unless otherwise noted)

БА	RAMETER	TEST CONDITIONS	V	V	Τ,	∠ = 25	С	–40°C to	85°C	UNIT
PA	RAMETER	TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNIT
	A port		0 V	0 V to 3.6 V		±0.1	±1		±5	۸
I _{off}	B port	$V_1 \text{ or } V_0 = 0 \text{ to } 3.6 \text{ V}$	0 V to 3.6 V	0 V		±0.1	±1		±5	μA
A or B port			3.6 V	3.6 V		±0.5	±2.5		±5	۵
I _{OZ} ⁽³⁾	B port	$V_{O} = V_{CCO}$ or GND,	0 V	3.6 V					±5	μA
	A port	$V_I = V_{CCI}$ or GND, $\overline{OE} = don't care$	3.6 V	0 V					±5	
			1.2 V to 3.6 V	1.2 V to 3.6 V					8	
I _{CCA}		$V_{I} = V_{CCI} \text{ or } GND, I_{O} = 0$	0 V	3.6 V					-2	μA
			3.6 V	0 V					8	
			1.2 V to 3.6 V	1.2 V to 3.6 V					8	
I _{CCB}		$V_{I} = V_{CCI} \text{ or } GND, I_{O} = 0$	0 V	3.6 V					8	μA
			3.6 V	0 V					-2	
I _{CCA} +	I _{CCB}	$V_{I} = V_{CCI} \text{ or } GND, I_{O} = 0$	1.2 V to 3.6 V	1.2 V to 3.6 V					16	μA
C _i	Control inputs	V ₁ = 3.3 V or GND	3.3 V	3.3 V		3.5			4.5	pF
Cio	A or B port	$V_0 = 3.3 \text{ V or GND}$	3.3 V	3.3 V		6			7	pF

V_{CCI} is the V_{CC} associated with the input port.
 V_{CCO} is the V_{CC} associated with the output port.
 For I/O ports, the parameter I_{OZ} includes the input leakage current.

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.2$ V (see Figure 10)

	FROM	то	V _{CCB} = 1.2 V	V _{CCB} = 1.5 V	V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V															
PARAMETER	(INPUT)	(OUTPUT)	ТҮР	ТҮР	ТҮР	ТҮР	ТҮР	UNIT														
t _{PLH}	А	В	3.1	2.6	2.5	3	3.5	20														
t _{PHL}	A	В	3.1	2.6	2.5	3	3.5	ns														
t _{PLH}	В	А	3.1	2.7	2.5	2.4	2.3	20														
t _{PHL}	U	A	3.1	2.7	2.5	2.4	2.3	ns														
t _{PZH}		А	5.3	5.3	5.3	5.3	5.3	20														
t _{PZL}	ŌĒ	A	5.3	5.3	5.3	5.3	5.3	ns														
t _{PZH}	ŌĒ	Р	5.1	4	3.5	3.2	3.1	20														
t _{PZL}	UE	В	В	B	В	В	В	В	В	В	В	B	B	В	В	В	5.1	4	3.5	3.2	3.1	ns
t _{PHZ}	OE	^	4.8 4.8		4.8	4.8	4.8	20														
t _{PLZ}	UE	A	4.8	4.8	4.8	4.8	4.8	ns														
t _{PHZ}	ŌĒ	ŌĒ	ŌĒ	P	4.7	4	4.1	4.3	5.1	~~~												
t _{PLZ}				OE B —	4.7	4	4.1	4.3	5.1	ns												

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.5 V \pm 0.1 V (see Figure 10)

				UUA																
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{ССВ} = ± 0.2	1.5 V I V	V _{ССВ} = ± 0.1		V _{ССВ} = ± 0.2		V_{CCB} = 3.3 V ± 0.3 V		UNIT								
		(001201)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX									
t _{PLH}	А	В	2.7	0.5	5.4	0.5	4.6	0.5	4.9	0.5	6.8	20								
t _{PHL}	A	Б	2.7	0.5	5.4	0.5	4.6	0.5	4.9	0.5	6.8	ns								
t _{PLH}	В	А	2.6	0.5	5.4	0.5	5.1	0.5	4.7	0.5	4.5	ns								
t _{PHL}	Б	A	2.6	0.5	5.4	0.5	5.1	0.5	4.7	0.5	4.5	115								
t _{PZH}		•	3.7	1.1	8.7	1.1	8.7	1.1	8.7	1.1	8.7	20								
t _{PZL}	ŌĒ	E A	3.7	1.1	8.7	1.1	8.7	1.1	8.7	1.1	8.7	ns								
t _{PZH}	ŌĒ	В	4.8	1.1	7.6	1.1	7.1	1	5.6	1	5.2									
t _{PZL}	0E	Б	4.8	1.1	7.6	1.1	7.1	1	5.6	1	5.2	ns								
t _{PHZ}		^	3.1	0.5	8.6	0.5	8.6	0.5	8.6	0.5	8.6									
t _{PLZ}	OE	E A -	3.1	0.5	8.6	0.5	8.6	0.5	8.6	0.5	8.6	ns								
t _{PHZ}		В	4.1	0.5	8.4	0.5	7.6	0.5	7.2	0.5	7.8	20								
t _{PLZ}	ŌĒ	OE	ŌĒ	OE	OE	ŌĒ	ŌĒ	ŌĒ	OE	D	4.1	0.5	8.4	0.5	7.6	0.5	7.2	0.5	7.8	ns

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.8 V \pm 0.15 V (see Figure 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{ССВ} = ± 0.1		V _{ССВ} = ± 0.1	= 1.8 V 15 V	V _{CCB} = ± 0.2		V _{ССВ} = ± 0.3		UNIT															
	(INFUT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX																
t _{PLH}	А	В	2.5	0.5	5.1	0.5	4.4	0.5	4	0.5	3.9	20															
t _{PHL}	A	D	2.5	0.5	5.1	0.5	4.4	0.5	4	0.5	3.9	ns															
t _{PLH}	В	А	2.5	0.5	4.6	0.5	4.4	0.5	3.9	0.5	3.7	20															
t _{PHL}	В	В	В	D	D	D	В	В	A	2.5	0.5	4.6	0.5	4.4	0.5	3.9	0.5	3.7	ns								
t _{PZH}		•	3	1	6.8	1	6.8	1	6.8	1	6.8	20															
t _{PZL}	ŌĒ	A	3	1	6.8	1	6.8	1	6.8	1	6.8	ns															
t _{PZH}	ŌĒ	В	4.6	1.1	8.2	1	6.7	0.5	5.1	0.5	4.5																
t _{PZL}	UE	В	4.6	1.1	8.2	1	6.7	0.5	5.1	0.5	4.5	ns															
t _{PHZ}	ŌĒ								<u> </u>	<u> </u>							•	2.8	0.5	7.1	0.5	7.1	0.5	7.1	0.5	7.1	
t _{PLZ}		E A –	2.8	0.5	7.1	0.5	7.1	0.5	7.1	0.5	7.1	ns															
t _{PHZ}	ŌĒ	- DE	ŌE	OE	HZ OE	В	3.9	0.5	7.8	0.5	6.9	0.5	6	0.5	5.8												
t _{PLZ}						ŌĒ	В	3.9	0.5	7.8	0.5	6.9	0.5	6	0.5	5.8	ns										

SCES565G-APRIL 2004-REVISED MARCH 2007

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 2.5 V \pm 0.2 V (see Figure 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = ± 0.7		V _{ССВ} = ± 0.1		V _{ССВ} = ± 0.2		V _{ССВ} = ± 0.3		UNIT													
	(INFUT)	(001201)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX														
t _{PLH}	А	В	2.4	0.5	4.7	0.5	3.9	0.5	3.1	0.5	2.8	~~													
t _{PHL}	A	Б	2.4	0.5	4.7	0.5	3.9	0.5	3.1	0.5	2.8	ns													
t _{PLH}	В	А	3	0.5	4.9	0.5	4	0.5	3.1	0.5	2.9	20													
t _{PHL}	В	В	A	3	0.5	4.9	0.5	4	0.5	3.1	0.5	2.9	ns												
t _{PZH}	OE	^	2.2	0.5	4.8	0.5	4.8	0.5	4.8	0.5	4.8	~~													
t _{PZL}	UE	A	2.2	0.5	4.8	0.5	4.8	0.5	4.8	0.5	4.8	ns													
t _{PZH}	ŌĒ	В	4.5	1.1	7.9	0.5	6.4	0.5	4.6	0.5	4	~~													
t _{PZL}	UE	Б	4.5	1.1	7.9	0.5	6.4	0.5	4.6	0.5	4	ns													
t _{PHZ}		DE A	1.8	0.5	5.1	0.5	5.1	0.5	5.1	0.5	5.1	20													
t _{PLZ}	OE		1.8	0.5	5.1	0.5	5.1	0.5	5.1	0.5	5.1	ns													
t _{PHZ}		В	3.6	0.5	7.1	0.5	6.3	0.5	5.1	0.5	3.9	20													
t _{PLZ}	ŌĒ	ŌĒ	ŌĒ	ŌĒ	ŌĒ	ŌĒ	ŌĒ	OE	ŌĒ	ŌĒ	OE	ŌĒ	ŌĒ	ŌĒ	D	3.6	0.5	7.1	0.5	6.3	0.5	5.1	0.5	3.9	ns

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 3.3 V \pm 0.3 V (see Figure 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{ССВ} = ± 0.1		V _{ССВ} = ± 0.1		V _{CCB} = ± 0.2		V _{ССВ} = ± 0.3		UNIT																		
	(INFUT)	(001201)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX																			
t _{PLH}	٨	В	2.3	0.5	4.5	0.5	3.7	0.5	2.9	0.5	2.5	20																		
t _{PHL}	A	Б	2.3	0.5	4.5	0.5	3.3	0.5	2.9	0.5	2.5	ns																		
t _{PLH}	D	А	3.5	0.5	6.8	0.5	3.9	0.5	2.8	0.5	2.5	20																		
t _{PHL}	В	В	В	В	D	A	3.5	0.5	6.8	0.5	3.9	0.5	2.8	0.5	2.5	ns														
t _{PZH}	OE	А	2	0.5	4	0.5	4	0.5	4	0.5	4	5																		
t _{PZL}	UE	A	2	0.5	4	0.5	4	0.5	4	0.5	4	ns																		
t _{PZH}	ŌĒ	В	4.5	1.1	7.8	0.5	6.2	0.5	4.5	0.5	3.9	20																		
t _{PZL}	0E	Б	4.5	1.1	7.8	0.5	6.2	0.5	4.5	0.5	3.9	ns																		
t _{PHZ}	ŌĒ																	^	1.7	0.5	4	0.5	4	0.5	4	0.5	4	20		
t _{PLZ}		DE A -	1.7	0.5	4	0.5	4	0.5	4	0.5	4	ns																		
t _{PHZ}	ŌĒ	ŌĒ	ŌĒ	ŌĒ	ŌE	ŌĒ	ŌĒ	ŌĒ	ŌE	ŌĒ	ŌĒ	ŌĒ	ŌĒ	ŌĒ	ŌĒ	ŌE	ŌĒ	ŌĒ	ŌĒ	В	3.4	0.5	6.9	0.5	6	0.5	4.8	0.5	4.2	20
t _{PLZ}																				ŌĒ	ŌĒ	D	3.4	0.5	6.9	0.5	6	0.5	4.8	0.5

Operating Characteristics

 $T_A = 25^{\circ}C$

F	PARAMETER		TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.2 V	V _{CCA} = V _{CCB} = 1.5 V	V _{CCA} = V _{CCB} = 1.8 V	V _{CCA} = V _{CCB} = 2.5 V	V _{CCA} = V _{CCB} = 3.3 V	UNIT
			CONDITIONO	TYP	TYP	TYP	TYP	TYP	
	A to B	Outputs enabled		1	1	1	1	1	
C (1)	Ou dis	Outputs disabled	C _L = 0, f = 10 MHz,	1	1	1	1	1	۶Ē
C _{pdA} ("	P to A	Outputs enabled	$t_r = t_f = 1 \text{ ns}$	12	12	12	13	14	pF
	B to A	Outputs disabled		1	1	1	1	1	
	A to B	Outputs enabled		12	12	12	13	14	
C (1)	AIUB	Outputs disabled	$C_{L} = 0,$	1	1	1	1	1	~ F
C _{pdB} ⁽¹⁾	P to A	Outputs enabled	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	1	1	1	1	1	pF
	B to A	Outputs disabled		1	1	1	1	1	

(1) Power dissipation capacitance per transceiver

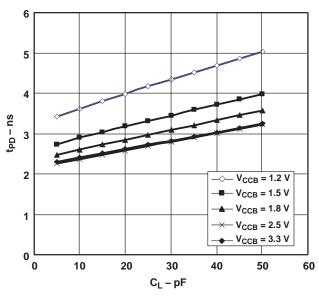
Table 1. Typical Total Static Power Consumption		·)
	\'LLA ' 'LL	. В/

v	V _{CCA}							
V _{CCB}	0 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	UNIT	
0 V	0	<0.5	<0.5	<0.5	<0.5	<0.5		
1.2 V	<0.5	<1	<1	<1	<1	1		
1.5 V	<0.5	<1	<1	<1	<1	1	۵	
1.8 V	<0.5	<1	<1	<1	<1	<1	- μΑ	
2.5 V	<0.5	1	<1	<1	<1	<1		
3.3 V	<0.5	1	<1	<1	<1	<1		

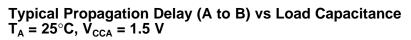


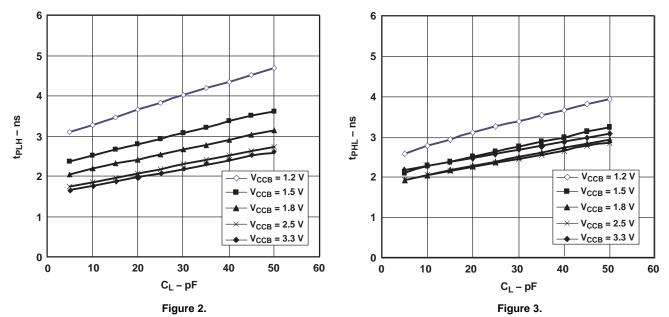
TYPICAL CHARACTERISTICS

Typical Propagation Delay (A to B) vs Load Capacitance $T_A = 25^{\circ}C$, $V_{CCA} = 1.2$ V

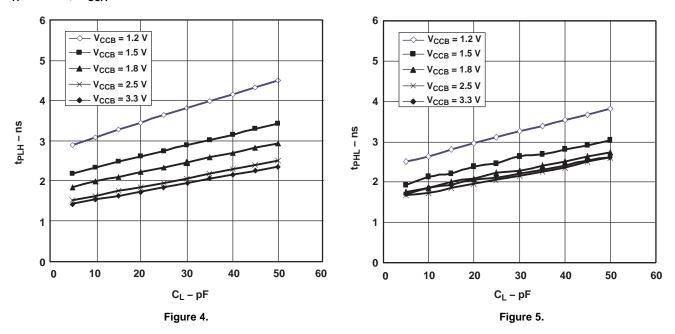


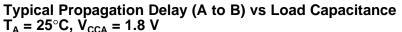


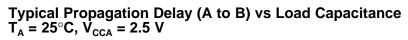


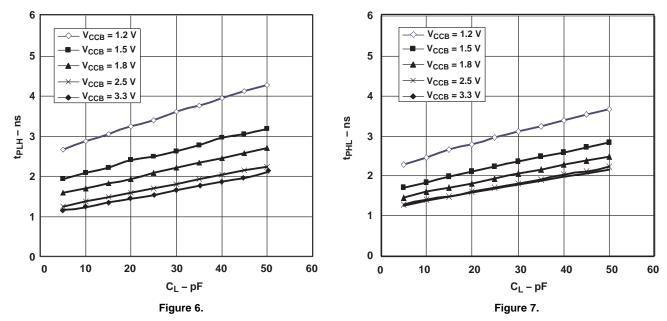


TYPICAL CHARACTERISTICS (continued)



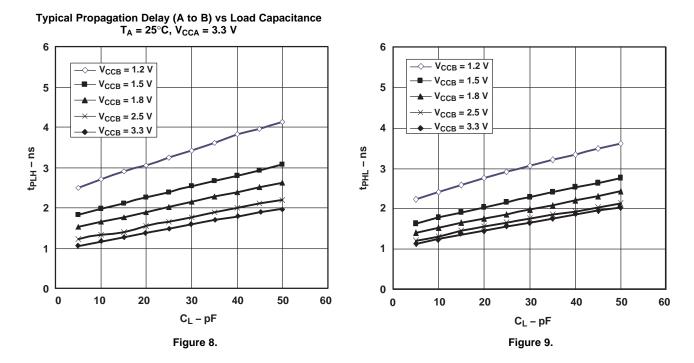




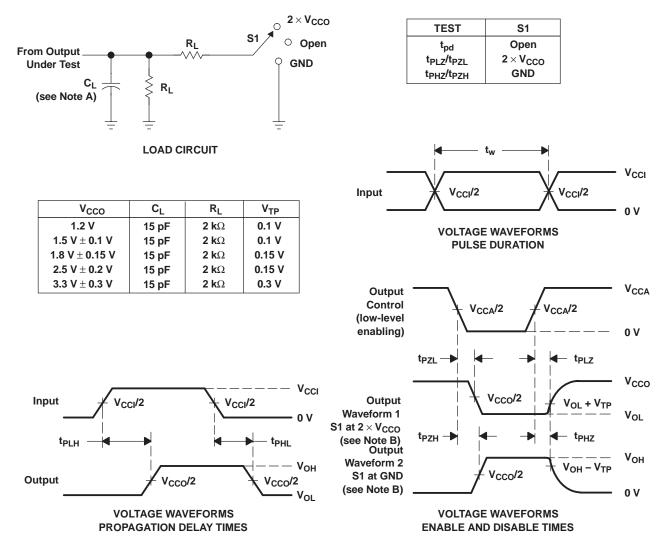




TYPICAL CHARACTERISTICS (continued)



SCES565G-APRIL 2004-REVISED MARCH 2007



PARAMETER MEASUREMENT INFORMATION

- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Q = 50 Ω, dv/dt ≥ 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZI} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. V_{CCI} is the V_{CC} associated with the input port.
 - I. V_{CCO} is the V_{CC} associated with the output port.

Figure 10. Load Circuit and Voltage Waveforms



24-Jan-2013

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
74AVCH8T245DGVRE4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
74AVCH8T245DGVRG4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
74AVCH8T245PWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
74AVCH8T245PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
74AVCH8T245RHLRG4	ACTIVE	QFN	RHL	24	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WP245	Samples
SN74AVCH8T245DGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245PWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245PWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245RHLR	ACTIVE	QFN	RHL	24	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WP245	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.



www.ti.com

24-Jan-2013

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS

Texas Instruments





TAPE AND REEL INFORMATION

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVCH8T245DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AVCH8T245PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74AVCH8T245RHLR	QFN	RHL	24	1000	180.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVCH8T245DGVR	TVSOP	DGV	24	2000	367.0	367.0	35.0
SN74AVCH8T245PWR	TSSOP	PW	24	2000	367.0	367.0	38.0
SN74AVCH8T245RHLR	QFN	RHL	24	1000	210.0	185.0	35.0

PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

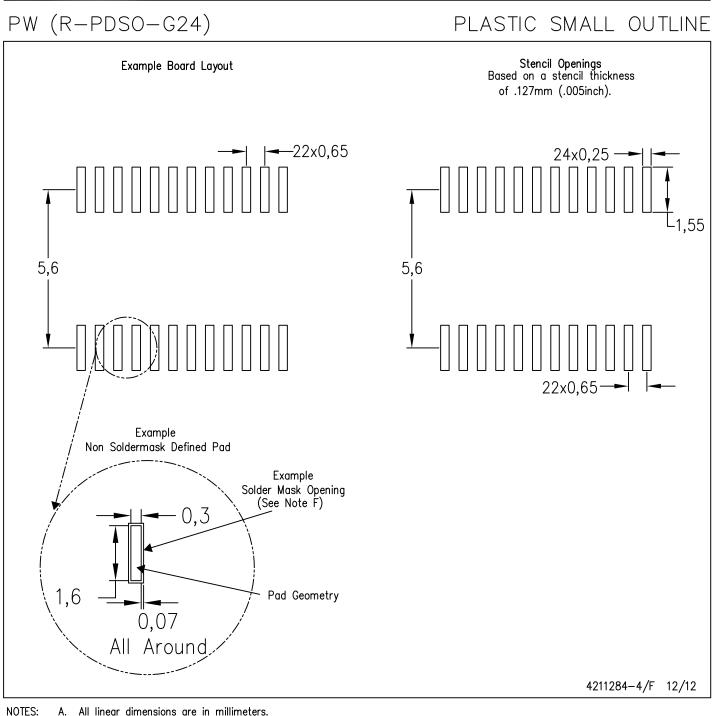
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



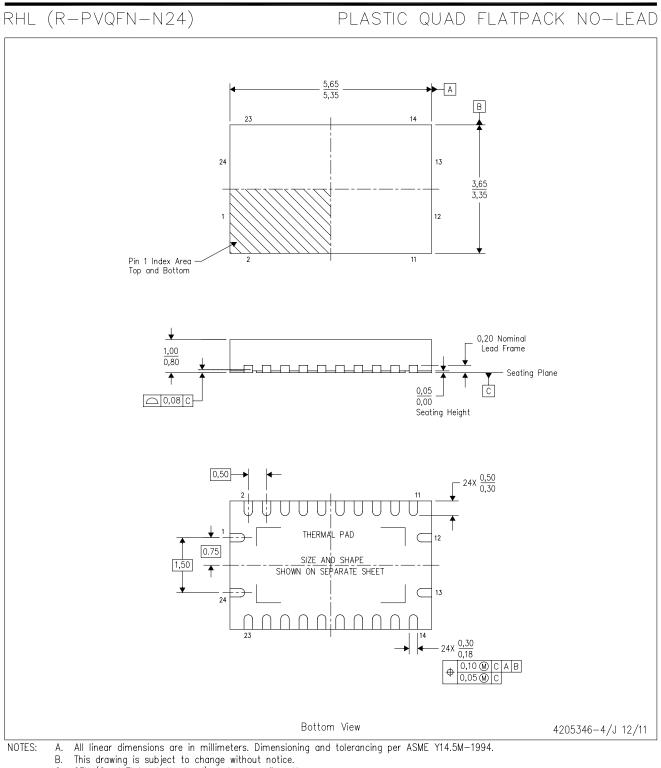


All linear dimensions are in millimeters. A.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations. E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

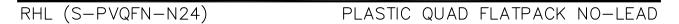


MECHANICAL DATA



- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. JEDEC MO-241 package registration pending.



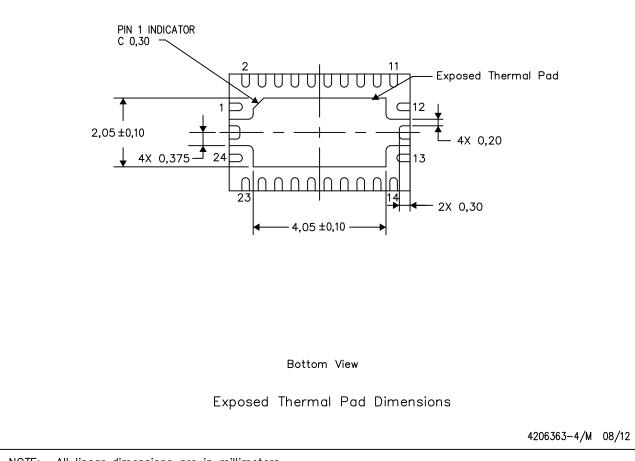


THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

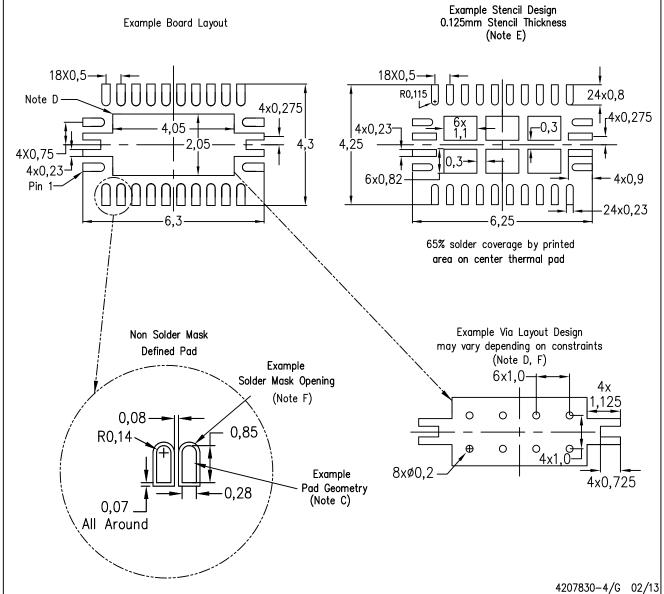
The exposed thermal pad dimensions for this package are shown in the following illustration.











NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.

D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.

- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ectivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated